

Rohs Compliant





DESCRIPTION

The GC4700 series diodes are specially processed PIN diodes designed for use in passive or active limiters at frequencies through Ku band.

Thirteen categories of devices are offered for flexibility in design of low, medium and high power limiters.

Low VB limiters have thinner I regions for faster turn-on time and better flat leakage. Microsemi also manufactures "gold doped" limiters for fastest turn on time. In addition, we manufacture high voltage dual junction limiters for superior peak and CW power handling.

This series of diodes meets RoHS requirements per EU Directive 2002/95/EC.

APPLICATIONS

A diode limiter is a power-sensitive variable attenuator that uses the non-linear properties of the diode to provide an impedance mismatch when sufficient amounts of RF power are incident on the device. The output power is reduced to a level that will not overdrive a receiver, burn out a mixer, etc. For varying input power levels in excess of the diode's threshold level, the limiter's output power tends to remain constant.

A passive limiter is one in which the limiter diodes are "turned on" by the RF signal itself. An active limiter is one in which the limiter diodes are "turned on" primarily by an external bias current typically supplied by a Schottky detector diode which senses the incident signal.

Since limiter diodes are not designed to dissipate large amounts of power, the limiter must reflect or divert the excess incident power back to the source or to another load (i.e. via a circulator, hybrid coupler, etc.).

Limiter diodes may be used in wave guides, coax, microstrip, stripline or other media. Single or cascaded devices may be used, depending on power levels.

ABSOLUTE MAXIMUM RATINGS AT 25° C (UNLESS OTHERWISE SPECIFIED)

Rating	Symbol	Value	Unit
Maximum Leakage Current @80% of minimum Rated Vb	lr	0.5	uA
Operating Temperature	Тор	-55 to +150	°C
Storage Temperature	T stg	-65 to +150	°C

IMPORTANT: For the most current data, consult our website: www.MICROSEMLcom

These devices are ESD sensitive and must be handled using ESD precautions.

KEY FEATURES

- Available as packaged devices or as chips for hybrid applications
- Low Loss
- Suitable for applications to 18Ghz
- Excellent flat leakage performance
- Low 1 dB compression point
- Gold Doped Diodes for Fast Turn On
- RoHS Compliant¹
- ¹ Most or our devices are supplied with Gold plated terminations. Other terminal finishes are available on request. Consult factory for details.

APPLICATIONS/BENEFITS

- Receiver protection circuits
- Amplifier Protection

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CHIP ELECTRICAL PARAMETERS @ 25°C (unless otherwise specified)								
Model #	V _b (Min)	C _{j0} (Typ)	C _{j-6} (Max)	C _{j-50} (Max)	R _s (Typ)	T _L (Typ)	θΡ¹ (Typ)	θP² (Max)
	I _R =10μΑ (Volts)	@0V (pF)	@-6V (pF)	@-50V (pF)	@10 mA (Ω)	(ns)	THERMAL RESISTANCE (°C/W)	THERMAL RESISTANCE (°C/W)
GC4701-00	20	0.20	0.15		1.5	5	20	100
GC4702-00	20	0.50	0.30		1.2	10	12	80
GC4711-00	45	0.20	0.15		1.5	10	15	80
GC4712-00	45	0.50	0.30		1.2	15	10	60
GC4713-00	45	0.70	0.50		1.0	20	6	40
GC4721-00	120	0.20	0.15		1.5	50	1.2	40
GC4722-00	120	0.60	0.30		1.0	50	0.5	20
GC4723-00	120	0.80	0.50		0.5	100	0.3	15
GC4731-00	15	0.12	0.10		2.0	5	30	120
GC4732-00	15	0.20	0.15		1.5	5	20	80
GC4741-00	30	0.12	0.10		2.0	7	20	100
GC4742-00	30	0.20	0.15		1.5	7	15	70
GC4750-002 ⁽³⁾	250			0.25 ⁽⁴⁾	3.0@50mA	300	4	10

Model Number	V _b (Min)	PEAK POWER P _{IN} @ 1 μ S (dBm)	TYPICAL LEAKAGE P _{out} (dBm)	TYPICAL THRESHOLD (dBm)	TYPICAL INS. LOSS I _L (dB)	MAXIMUM CW POWER (Watts)
GC4701	20	+50	+22	+10	0.1	2
GC4702	20	+53	+24	+10	0.2	3
GC4711	45	+53	+27	+15	0.1	3
GC4712	45	+56	+29	+15	0.2	4
GC4713	45	+59	+31	+15	0.2	5
GC4721	120	+60	+39	+20	0.1	5
GC4722	120	+63	+41	+20	0.2	10
GC4723	120	+66	+44	+20	0.2	15
GC4731	15	+47	+19	+7	0.1	2
GC4732	15	+50	+22	+4	0.1	3
GC4741	30	+47	+24	+12	0.1	3
GC4742	30	+50	+27	+12	0.1	4
GC4750	250	+56 @10uS	+44	+31	0.2	50

Notes

- 1) Pulse length 1 microsecond.
- 2) As measured in style 30 package
- 3) Available in 002 style or 115-2 package styles 4) C_J for 2 junctions in parallel @ V_R =50V

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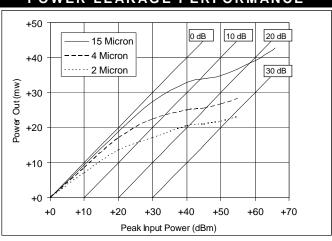


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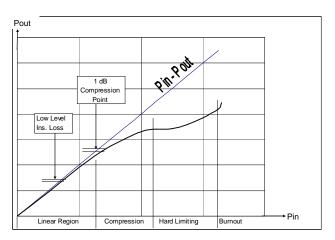


POWER LEAKAGE PERFORMANCE



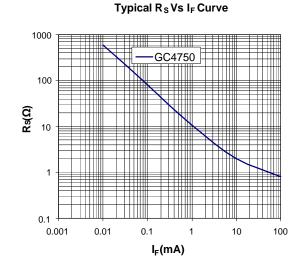
Typical Power Leakage vs I Region Thickness

TRANSFER CHARACTERISTICS

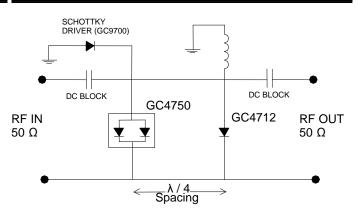


Typical Limiter Transfer Characteristics

SERIES RESISTANCE



HIGH POWER DUAL LIMITER DESIGN



2 Stage Limiter with Schottky Driver

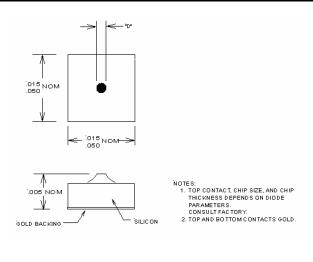




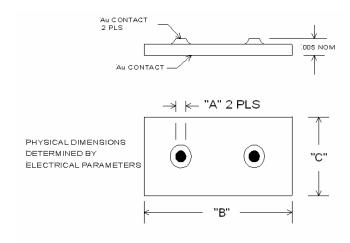




PACKAGE STYLE 00



DUAL CHIP STYLE 002



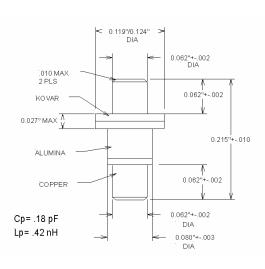
Notes:

Order as GC47xx – 00

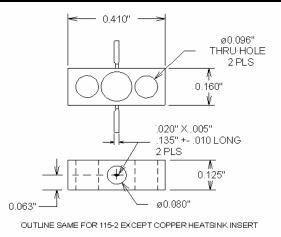
Notes:

- Order as GC47xx - 002

PACKAGE SYLE 30



PACKAGE STYLE 115-2



Notes:

- Order as GC47xx – 30

Notes:

Order as GC47xx – 115-2

OTHER PACKAGE STYLES AVAILABLE ON REQUEST CONSULT FACTORY



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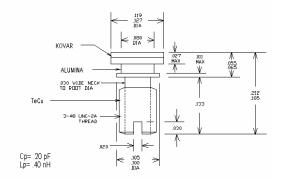




PACKAGE STYLE 35

| 1119 | 124 | | 1027 | | 1085 | 1097 | | 1085 | 1097 | | 1085 | 1097 | | 1085 | 1097 | | 1085 | 1097 | | 1083 | | 1085 | 1097 | | 1083 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085 | 1085

PACKAGE SYLE 42



Notes:

Notes:

- Order as GC47xx - 35 - Order as GC47xx - 42
OTHER PACKAGE STYLES AVAILABLE ON REQUEST
CONSULT FACTORY



GC4701 - GC4750

CONTROL DEVICES - LIMITERS DIODES

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NOTES

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